

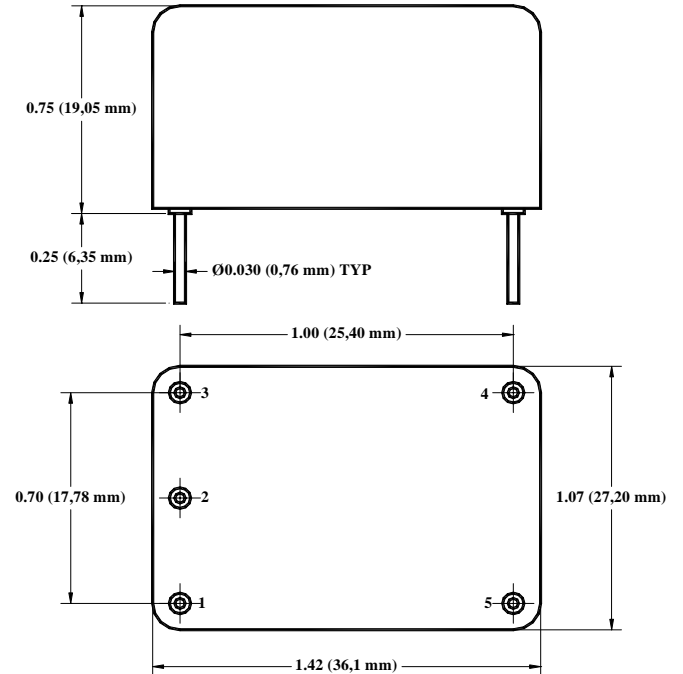
Rev. J

**OM-X8GXXXXX-X Series
HF/UHF OCXO Low Power**

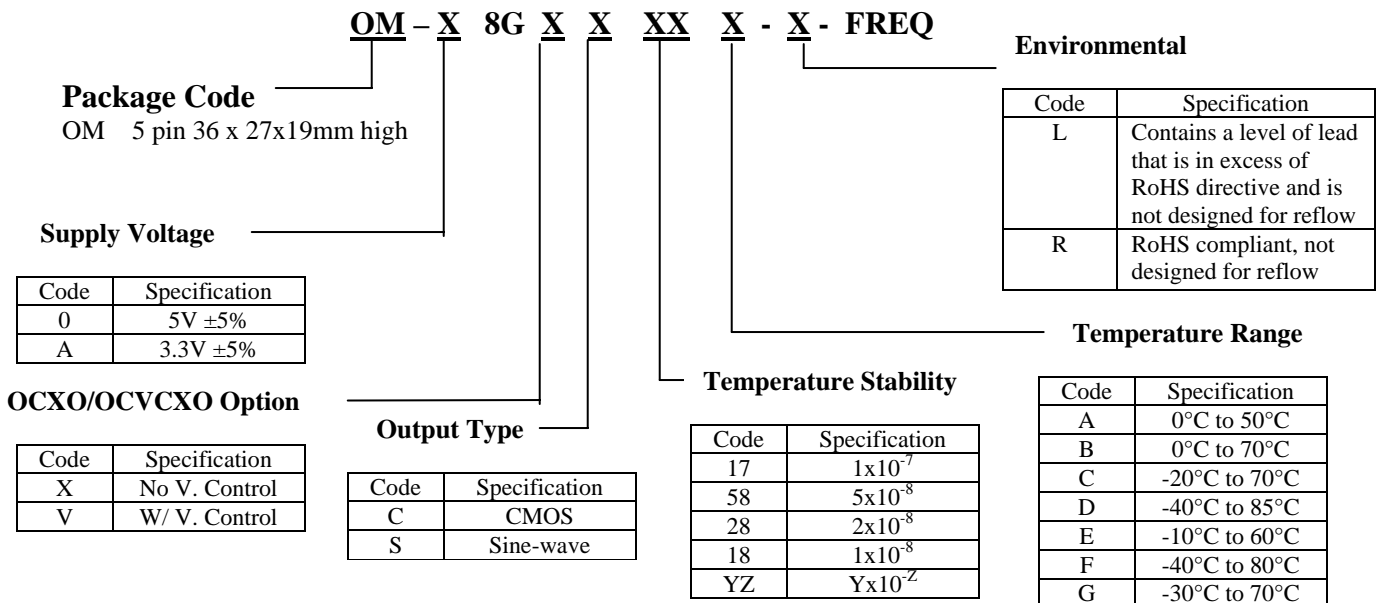
Description: The OM-X8GXXXXX Series of Oven Controlled Crystal Oscillators (OCXO) provides High and Ultra High Frequency with SC-cut stability performance, extremely low phase noise and power consumption, with either CMOS or Sine-wave output in a standard 1.4x1” package – “Europack”.

Features

- Very Low Power Consumption
- Very Low Phase Noise
- Excellent SC-cut Frequency Stability
- Ultra High Frequency – up to 1 GHz
- CMOS, Sine-Wave outputs available
- Stratum3E available
- COTS/Dual use



Creating a Part Number



OM-X8GXXXXX-X Series HF/UHF OCXO Low Power

Rev. J

Specifications

Parameter	Symb	Condition	Min	Typ	Max	Unit	Note
-----------	------	-----------	-----	-----	-----	------	------

Absolute Maximum Ratings

Input Break Down Voltage	V _{cc}		-0.5		5.5	V	
Storage temp.	T _s		-40		85	°C	
Contr. Voltage	V _c		1		9	V	

Electrical (1)

Frequency Range	F	CMOS Sine-wave	30 30		200 1,000	MHz	
Input Voltage	V _{cc}		3.135 4.75	3.30 5.0	3.465 5.25	V	A 0
Input Current	I _{cc}				90 160	mA	@ 100 MHz, 3.3V @ 622 MHz, 3.3V
Frequency Stability	ΔF/F	vs. Temperature vs. V _{cc} aging		±50 ±2 ±0.1 ±0.5		ppb ppb/V ppm/year ppm	See chart First Year 15 years
Calibration	ΔF/F	As shipped, 25°C		±0.1		ppm	
Load		CMOS Sine		15pF/10KOhm Internally AC-coupled 50 Ohm			
Duty cycle		@50%	45	50	55	%	CMOS
Rise/Fall time	T _r /T _f	20 to 80 %		3		ns	CMOS
Logic "1" level	V _{oh}	CMOS	0.9V _{cc}			V	
Logic "0" level	V _{ol}	CMOS			0.1V _{cc}	V	
Output power	P	Sinewave Into 50 Ohm	0 4	3 7		dBm	3.3V 5.0V
Start up time	T _s			2	10	ms	
Phase jitter		1σ		0.4 0.2	1 0.4	ps	100 Hz to 20 MHz 12 KHz to 20 MHz
Subharmonics		Sine CMOS, Sine		-45	-40 none	dBc	F>250MHz F< 250 MHz
Spurious					-60	dBc	
Harmonics		Sine-wave		-30	-25	dBc	
SSB Phase Noise		@ 10 Hz @ 100 Hz @ 1 KHz @ 10 KHz @ 100 KHz		-100 -120 -140 -160 -165		dBc/Hz	@ 100 MHz
SSB Phase Noise		@ 10 Hz @ 100 Hz @ 1 KHz @ 10 KHz @ 100 KHz		-80 -90 -120 -145 -150		dBc/Hz	@ 622 MHz; Sine
Input Impedance				> 10KOhm			
Control voltage	V _c		0		4.0	V	V _{cc} code "0"
			0		2.8	V	V _{cc} code "A"
Modulation bandwidth	MB			2Hz			Contact Factory for wider MB
Deviation		0V to V _c max	±0.5	±1.0		ppm	

Note 1. All parameters, unless otherwise specified, are at nominal conditions, ie: T=25°C, Nominal V_{cc} & Nominal Load.



**FREQUENCY
CONTROLS, INC.**

357 Beloit Street, P.O. Box 457, Burlington, WI 53105-0457 U.S.A. Phone 262/763-3591 FAX 262/763-2881

Email: nelsales@nelfc.com www.nelfc.com

Rev. J

OM-X8GXXXXX-X Series HF/UHF OCXO Low Power

Environmental and Mechanical

Operating temp. range	0°C to 70°C , -40°C to 85°C, see chart, page 1
Mechanical Shock	Per MIL-STD-202, Method 213, Cond. E
Thermal Shock	Per MIL-STD-883, Method 1011, Cond. A
Vibration	Per MIL-STD-883, Method 2007, Cond. A
Soldering Conditions	260°C for 10 s leads only
Hermetic Seal	Leak rate less than 5×10^{-8} atm.cc/s of helium

Electrical Connections

Pin Out	Pin #1- Voltage Control ; Pin #2 – Vref ; Pin #3 – Vcc; Pin#4 – Output, CMOS or Sine; Pin#5 - GND
----------------	---

